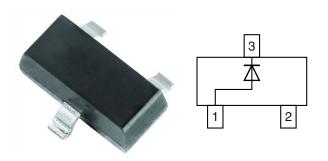


### Vishay Semiconductors

# **Small Signal Fast Switching Diode**



#### **MECHANICAL DATA**

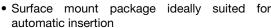
Case: SOT-23

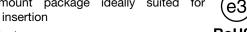
Weight: approx. 8.8 mg Packaging codes/options:

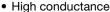
18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

#### **FEATURES**

- · Silicon epitaxial planar diode
- · Ultra fast switching speed







- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade
- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

PARTS TABLE						
PART	ORDERING CODE	INTERNAL CONSTRUCTION	TYPE MARKING	REMARKS		
BAS16	BAS16-E3-08 or BAS16-E3-18	Single diade	A6	Tape and reel		
	BAS16-HE3-08 or BAS16-HE3-18	Single diode	AO	rape and reei		

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Non repetitive peak reverse voltage		V <sub>RM</sub>	100	V	
Repetitive peak reverse voltage = working peak reverse voltage = DC blocking voltage		$V_{RRM} = V_{RWM} = V_{R}$	75	V	
Peak forward surge current	t <sub>p</sub> = 1 s	I <sub>FSM</sub>	1	Α	
reak lorward surge current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	2	Α	
Average forward current	Half wave rectification with resistive load and $f \ge 50$ MHz, on ceramic substrate 8 mm x 10 mm x 0.7 mm	I <sub>F(AV)</sub>	150	mA	
Forward current	On ceramic substrate 8 mm x 10 mm x 0.7 mm	I <sub>F</sub>	300	mA	
Power dissipation	On ceramic substrate 8 mm x 10 mm x 0.7 mm	P <sub>tot</sub>	350	mW	

THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Junction ambient	On ceramic substrate 8 mm x 10 mm x 0.7 mm	R <sub>thJA</sub>	357	K/W	
Junction and storage temperature range		$T_j = T_{stg}$	-55 to +150	°C	
Operating temperature range		T <sub>op</sub>	-55 to +150	°C	



# Vishay Semiconductors

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I <sub>F</sub> = 1 mA	V <sub>F</sub>			0.715	V
Forward voltage	I <sub>F</sub> = 10 mA	V <sub>F</sub>			855	mV
Forward voitage	$I_F = 50 \text{ mA}$	V <sub>F</sub>			1	V
	I <sub>F</sub> = 150 mA	V <sub>F</sub>			1.25	V
	V <sub>R</sub> = 75 V	I <sub>R</sub>			1	μΑ
Reverse current	$V_R = 75 \text{ V}, T_j = 150 ^{\circ}\text{C}$	I <sub>R</sub>			50	μA
	V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			30	μA
Diode capacitance	$V_R = 0$ , $f = 1$ MHz	C <sub>D</sub>			4	pF
Reverse recovery time	$I_F$ = 10 mA to $I_R$ = 1 mA, $V_R$ = 6 V, $R_L$ = 100 $\Omega$	t <sub>rr</sub>			6	ns

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

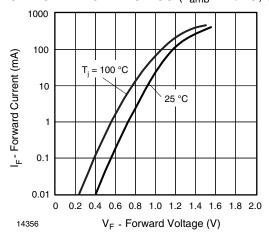


Fig. 1 - Forward Current vs. Forward Voltage

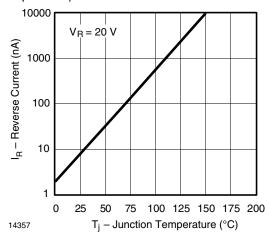
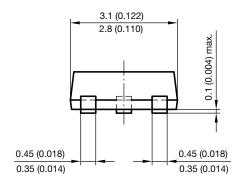
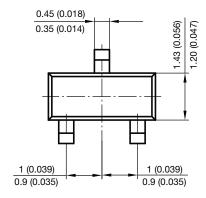


Fig. 2 - Reverse Current vs. Junction Temperature

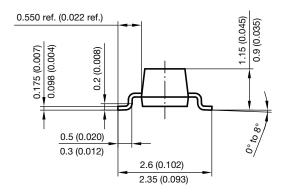
# Vishay Semiconductors

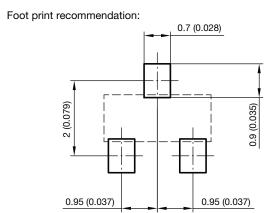
#### PACKAGE DIMENSIONS in millimeters (inches): SOT-23





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